

## Solid State Electronic Devices 7th Edition

Microelectronic Circuits by Sedra and Smith has served generations of electrical and computer engineering students as the best and most widely-used text for this required course. Respected equally as a textbook and reference, "Sedra/Smith" combines a thorough presentation of fundamentals with an introduction to present-day IC technology. It remains the best text for helping students progress from circuit analysis to circuit design, developing design skills and insights that are essential to successful practice in the field. Significantly revised with the input of two new coauthors, slimmed down, and updated with the latest innovations, Microelectronic Circuits, Eighth Edition, remains the gold standard in providing the most comprehensive, flexible, accurate, and design-oriented treatment of electronic circuits available today.

Modern Semiconductor Devices for Integrated Circuits, First Edition introduces readers to the world of modern semiconductor devices with an emphasis on integrated circuit applications. KEY TOPICS: Electrons and Holes in Semiconductors; Motion and Recombination of Electrons and Holes; Device Fabrication Technology; PN and Metal-Semiconductor Junctions; MOS Capacitor; MOS Transistor; MOSFETs in ICs—Scaling, Leakage, and Other Topics; Bipolar Transistor. MARKET: Written by an experienced teacher, researcher, and expert in industry practices, this succinct and forward-looking text is appropriate for anyone interested in semiconductor devices for integrated circuits, and serves as a suitable reference text for practicing engineers.

One of the most comprehensive, clearly written books on electronic technology, Simpon's invaluable guide offers a concise and practical overview of the basic principles, theorems, circuit behavior and problem-solving procedures of this intriguing and fast-paced science. Examines a broad spectrum of topics, such as atomic structure, Kirchhoff's laws, energy, power, introductory circuit analysis techniques, Thevenin's theorem, the maximum power transfer theorem, electric circuit analysis, magnetism, resonance semiconductor diodes, electron current flow, and much more. Smoothly integrates the flow of material in a nonmathematical format without sacrificing depth of coverage or accuracy to help readers grasp more complex concepts and gain a more thorough understanding of the principles of electronics. Includes many practical applications, problems and examples emphasizing troubleshooting, design, and safety to provide a solid foundation in the field of electronics. An ideal reference source for electronic engineering technicians and those involved in the electronic technology field.

This book is designed to help readers gain a basic understanding of semiconductor devices and the physical operating principles behind them. This two-fold approach 1) provides the user with a sound understanding of existing devices, and 2) helps them develop the basic tools with which they can later learn about applications and the latest devices. The piece provides

one of the most comprehensive treatments of all the important semiconductor devices, and reflects the most current trends in the technology and theoretical understanding of the devices.

FEATURES/BENEFITS \*NEW--Thoroughly updated to reflect the most current trends in the technology and theoretical understanding of devices. \*NEW--Expanded description of silicon Czochralski growth, wafer production, and vapor phase epitaxy (Ch. 1). \*NEW--Clearer discussion of chemical bonding, energy band formation and hole transport (Chs. 2, 3 and 4). \*NEW--Consolidated coverage of p-n junction diodes and its applications (Ch. 5). \*NEW--Greatly expanded/updated discussion of device fabrication processes (Ch. 5 and appendices). \*NEW--Earlier discussion of MOS devices (Ch. complementary MOS field effect transistors (MOSFETs) in integrated circuits today. \*NEW--Major revision of chapter on Field Effect Transistors (Ch. 6)--Both in the underlying theory as well as discussion of a variety of short channel, high field and hot carrier effects in scaled, ultra-small MOSFETs. Includes extensive discussions of the current-voltage and capacitance-voltage characteristics of these devices--and the information that can be gleaned from such measurements. \*NEW--Updated chapter on Bipolar Junction Transistors (BJTs) (Ch. 7)--To reflect current technology. Describes higher-order effects (including the Kirk effect and Webster effect); discusses the Gummel-Poon model (which is more elaborate and physically more accurate than the Ebers-Moll model); and updates the fabrication aspects of BJTs. \*NEW--Consolidated coverage of optoelectronic devices in a single chapter (Ch. 8)--Brings the discussion of semiconductor lasers into the same chapter as LEDs and detectors \*Reflects the growing importance of optoelectronics. \*NEW--Updated coverage of integrated circuits (Ch. concerted shift to CMOS applications, such as logic and memory integrated circuits. \*NEW--A section on the insulated gate bipolar transistor (Ch. 11)--A device that is gradually supplanting the semiconductor-controlled rectifier. \*NEW--Real data--Wherever feasible, replaces idealized current-voltage and capacitance-voltage plots with real data.

Proceedings of an International Symposium Held October 6-8, 1971, in Wildbad, Germany

Power Electronics and Motor Drives

Semiconductor Physics and Devices

From Bulk to Nano

Solid-state Electronics and Photonics in Biology and Medicine 6

An Introduction

***This second edition of the highly acclaimed RF Power Amplifiers has been thoroughly revised and expanded to reflect the latest challenges associated with power transmitters used in communications systems. With more rigorous treatment of many concepts, the new edition includes a unique combination of class-tested analysis and industry-proven design techniques. Radio frequency (RF) power amplifiers are the fundamental building blocks used in a vast variety of wireless communication circuits, radio and TV broadcasting transmitters, radars, wireless energy transfer, and industrial processes. Through a combination***

**of theory and practice, RF Power Amplifiers, Second Edition provides a solid understanding of the key concepts, the principle of operation, synthesis, analysis, and design of RF power amplifiers. This extensive update boasts: up to date end of chapter summaries; review questions and problems; an expansion on key concepts; new examples related to real-world applications illustrating key concepts and brand new chapters covering 'hot topics' such as RF LC oscillators and dynamic power supplies. Carefully edited for superior readability, this work remains an essential reference for research & development staff and design engineers. Senior level undergraduate and graduate electrical engineering students will also find it an invaluable resource with its practical examples & summaries, review questions and end of chapter problems. Key features:**

- A fully revised solutions manual is now hosted on a companion website alongside new simulations.
- Extended treatment of a broad range of topologies of RF power amplifiers.
- In-depth treatment of state-of-the art of modern transmitters and a new chapter on oscillators.
- Includes problem-solving methodology, step-by-step derivations and closed-form design equations with illustrations.

**The 4th edition of this highly successful textbook features copious material for a complete upper-level undergraduate or graduate course, guiding readers to the point where they can choose a specialized topic and begin supervised research. The textbook provides an integrated approach beginning from the essential principles of solid-state and semiconductor physics to their use in various classic and modern semiconductor devices for applications in electronics and photonics. The text highlights many practical aspects of semiconductors: alloys, strain, heterostructures, nanostructures, amorphous semiconductors, and noise, which are essential aspects of modern semiconductor research but often omitted in other textbooks. This textbook also covers advanced topics, such as Bragg mirrors, resonators, polarized and magnetic semiconductors, nanowires, quantum dots, multi-junction solar cells, thin film transistors, and transparent conductive oxides. The 4th edition includes many updates and chapters on 2D materials and aspects of topology. The text derives explicit formulas for many results to facilitate a better understanding of the topics. Having evolved from a highly regarded two-semester course on the topic, The Physics of Semiconductors requires little or no prior knowledge of solid-state physics. More than 2100 references guide the reader to historic and current literature including original papers, review articles and topical books, providing a go-to point of reference for experienced researchers as well.**

**A modern and concise treatment of the solid state electronic devices that are fundamental to electronic systems and information technology is provided in this book. The main devices that comprise semiconductor integrated circuits are covered in a clear manner accessible to the wide range of scientific and engineering disciplines that are impacted by this technology. Catering to a wider audience is becoming increasingly important as the field of electronic materials and devices becomes more interdisciplinary, with applications in biology, chemistry and electro-mechanical devices (to name a few) becoming more prevalent. Updated and state-of-the-art advancements are included along with emerging trends in electronic devices and their applications. In addition, an appendix containing the relevant physical background will be included to assist readers from different disciplines and provide a review for those more familiar with the area. Readers of this book can expect to derive a solid foundation for understanding modern electronic devices and also be prepared for future**

***developments and advancements in this far-reaching area of science and technology.***

***"This is the fifth edition of the most widely used introductory book on semiconductor materials, physics, devices and technology. The book was written with two basic goals in mind: 1) develop the basic semiconductor physics concepts to understand current and future devices; 2) provide a sound understanding of current semiconductor devices and technology so that their applications to electronic and optoelectronic circuits and systems can be appreciated."--BOOK JACKET.Title Summary field provided by Blackwell North America, Inc. All Rights Reserved***

***Fundamentals of Solid State Engineering***

***Solid State Physics***

***Advances and Trends***

***The Physics of Semiconductors***

***Introduction to Microelectronic Fabrication***

***Devices, Drivers and Applications***

**An accessible introduction to all important aspects of electric machines, covering dc, induction, and synchronous machines. Also addresses modern techniques of control, power electronics, and applications. Exposition builds from first principles, making this book accessible to a wide audience. Contains a large number of problems and worked examples.**

**In our abundant computing infrastructure, performance improvements across most all application spaces are now severely limited by the energy dissipation involved in processing, storing, and moving data. The exponential increase in the volume of data to be handled by our computational infrastructure is driven in large part by unstructured data from countless sources. This book explores revolutionary device concepts, associated circuits, and architectures that will greatly extend the practical engineering limits of energy-efficient computation from device to circuit to system level. With chapters written by international experts in their corresponding field, the text investigates new approaches to lower energy requirements in computing. Features • Has a comprehensive coverage of various technologies • Written by international experts in their corresponding field • Covers revolutionary concepts at the device, circuit, and system levels**

**This introductory book assumes minimal knowledge of the existence of integrated circuits and of the terminal behavior of electronic components such as resistors, diodes, and MOS and bipolar transistors. It presents to readers the basic information necessary for more advanced processing and design books. Focuses mainly on the basic processes used in fabrication, including lithography, oxidation, diffusion, ion implementation, and thin film deposition. Covers interconnection technology, packaging, and yield. Appropriate for readers interested in the area of fabrication of solid state devices and integrated circuits.**

**Aims of the Book:**The foremost and primary aim of the book is to meet the requirements of students pursuing following courses of study:1.Diploma in Electronics and Communication Engineering(ECE)-3-year course offered by various Indian and foreign polytechnics and technical institutes like city and guilds of London Institute(CGLI).2.B.E.(Elect.& Comm.)-4-year course offered by various Engineering Colleges.efforts have beenmade to cover the papers:Electronics-I & II and Pulse and Digital Circuits.3.B.Sc.(Elect.)-3-Year vocationalised course recently introduced by Approach.

**Advances in Materials Science and Engineering  
Compact Models for Integrated Circuit Design (Open Access)  
Circuit Analysis and Design  
Solid State Electronic Devices  
RF Power Amplifiers  
Microelectronics**

Power Electronics and Motor Drives: Advances and Trends, Second Edition is the perfect resource to keep the electrical engineer up-to-speed on the latest advancements in technology, equipment and applications. Carefully structured to include both traditional topics for entry-level and more advanced applications for the experienced engineer, this reference sheds light on the rapidly growing field of power electronic operations. New content covers converters, machine models and new control methods such as fuzzy logic and neural network control. This reference will help engineers further understand recent technologies and gain practical understanding via its inclusion of many industrial applications. Further supported by a glossary per chapter, this book gives engineers and researchers a critical reference to learn from real-world examples and make future decisions on power electronic technology and applications. Provides many practical examples of industrial applications Updates on the newest electronic topics with content added on fuzzy logic and neural networks Presents information from an expert with decades of research and industrial experience

Market\_Desc: · Graduate and Advanced Undergraduate Students of Electrical Engineering About The Book: This comprehensive introduction to the elementary theory and properties of semiconductors describes the basic physics of semiconductor materials and technologies for the fabrication of semiconductor devices. Addresses approaches to modeling and provides details on measurement techniques. It also includes numerous illustrative examples and graded problems. Provides a multidisciplinary introduction to quantum mechanics, solid state physics, advanced devices, and fabrication Covers wide range of topics in the same style and in the same notation Most up to date developments in semiconductor physics and nano-engineering Mathematical derivations are carried through in detail with emphasis on clarity Timely application areas such as biophotonics , bioelectronics

This Solution Manual, a companion volume of the book, Fundamentals of Solid-State Electronic Devices, provides the solutions to selected problems listed in the book. Most of the solutions are for the selected problems that had been assigned to the engineering undergraduate students who were taking an introductory device core course using this book. This Solution Manual also contains an extensive appendix which illustrates the application of the fundamentals to solutions of state-of-the-art transistor reliability problems which have been taught to advanced undergraduate and graduate students. This book is also available as a set with Fundamentals of Solid-State Electronic Devices and Fundamentals of Solid-State Electronics — Study Guide.

Pearson New International Edition

Principles, Techniques and Applications  
Microelectronic Circuits  
The Physics of Instabilities in Solid State Electron Devices  
Power Electronics  
An Introduction Including Nanophysics and Applications

*During the past 20 years, solid state physics has become one of the major branches of physics. 1-2 Today over one-third of all scientific articles published in physics deal with solid state 3 topics. During the last two decades, there has also been rapid growth of scientific computation in a wide variety of fields. -5 The combination of solid state physics and computation may be termed computational solid state physics. This emerging field is distinguished from theoretical solid state physics only to the extent that electronic computers rather than slide rules or backs of envelopes are used to solve numerical or logical problems, test scientific hypotheses, and discover the essential physical content of formal mathematical theories. Papers in computational solid state physics are widely scattered in the literature. They can be found in the traditional physics journals and review series, such as The Physical Review and Solid State Physics; in more specialized publications, such as Journal of Computational Physics, Computer Physics Communications, and Methods in Computational Physics; and in the proceedings of a number of recent conferences and seminar courses. - Plans for holding an International Symposium on Computational Solid State Physics in early October 1971 were formulated by Dr.*

*Students entering today's engineering fields will find an increased emphasis on practical analysis, design, and control. They must be able to translate their advanced programming abilities and sound theoretical backgrounds into superior problem-solving skills. Electromechanical Systems and Devices facilitates the creation of critical problem-solving*

*This book fills a gap between many of the basic solid state physics and materials science books that are currently available. It is written for a mixed audience of electrical engineering and applied physics students who have some knowledge of elementary undergraduate quantum mechanics and statistical mechanics. This book, based on a successful course taught at MIT, is divided pedagogically into three parts: (I) Electronic Structure, (II) Transport Properties, and (III) Optical Properties. Each topic is explained in the context of bulk materials and then extended to low-dimensional materials where applicable. Problem sets review the content of each chapter to help students to understand the material described in each of the chapters more deeply and to prepare them to master the next chapters. Most of the recent texts on compact modeling are limited to a particular class of semiconductor devices and do not provide comprehensive coverage of the field. Having a single comprehensive reference for the compact models of most commonly used semiconductor devices (both active and passive) represents a significant advantage for the reader. Indeed, several kinds of semiconductor devices are routinely encountered in a single IC design or in a single modeling support group. Compact Modeling includes mostly the material that after several years of IC design applications has been found both theoretically sound and practically significant. Assigning the individual chapters to the groups responsible for the definitive work on the subject assures the highest possible degree of expertise on each of the covered models.*

*Solid state electronic devices*

*A Quantum Physics Approach*

*Solid State Electronics Devices (For MAKAUT), 3rd Edition*

*Solid State Devices and Technology*

*Fundamentals of Solid-State Electronics*

*Semiconductor Device Fundamentals*

The past three decades have been a period where useful current and voltage instabilities in solids have progressed from exciting research problems to a wide variety of commercially available devices. Materials and electronics research has led to devices

such as the tunnel (Esaki) diode, transferred electron (Gunn) diode, avalanche diodes, real-space transfer devices, and the like. These structures have proven to be very important in the generation, amplification, switching, and processing of microwave signals up to frequencies exceeding 100 GHz. In this treatise we focus on a detailed theoretical understanding of devices of the kind that can be made unstable against circuit oscillations, large amplitude switching events, and in some cases, internal rearrangement of the electric field or current density distribution. The book is aimed at the semiconductor device physicist, engineer, and graduate student. A knowledge of solid state physics on an elementary or introductory level is assumed. Furthermore, we have geared the book to device engineers and physicists desirous of obtaining an understanding substantially deeper than that associated with a small signal equivalent circuit approach. We focus on both analytical and numerical treatment of specific device problems, concerning ourselves with the mechanism that determines the constitutive relation governing the device, the boundary conditions (contact effects), and the effect of the local circuit environment.

This junior level electronics text provides a foundation for analyzing and designing analog and digital electronics throughout the book. Extensive pedagogical features including numerous design examples, problem solving technique sections, Test Your Understanding questions, and chapter checkpoints lend to this classic text. The author, Don Neamen, has many years experience as an Engineering Educator. His experience shines through each chapter of the book, rich with realistic examples and practical rules of thumb. The Third Edition continues to offer the same hallmark features that made the previous editions such a success. Extensive Pedagogy: A short introduction at the beginning of each chapter links the new chapter to the material presented in previous chapters. The objectives of the chapter are then presented in the Preview section and then are listed in bullet form for easy reference. Test Your Understanding Exercise Problems with provided answers have all been updated. Design Applications are included at the end of chapters. A specific electronic design related to that chapter is presented. The various stages in the design of an electronic thermometer are explained throughout the text. Specific Design Problems and Examples are highlighted throughout as well. Special Features \*Computer-based exercises and homework problems -- unique to this text and comprising 25% of the total number of problems -- encourage students to address realistic and challenging problems, experiment with what if scenarios, and easily obtain graphical outputs. Problems are designed to progressively enhance MATLAB-use proficiency, so students need not be familiar with MATLAB at the start of your course. Program scripts that are answers to exercises in the text are available at no charge in electronic form (see Teaching Resources below). \*Supplement and Review Mini-Chapters after each of the text's three parts contain an extensive review list of terms, test-like problem sets with answers, and detailed suggestions on supplemental reading to reinforce students' learning and help them prepare for exams. \*Read-Only Chapters, strategically placed to provide a change of pace during the course, provide informative, yet enjoyable reading for students. \*Measurement Details and Results samples offer students a realistic perspective on the seldom-perfect nature of device characteristics,

contrary to the way they are often represented in introductory texts. Content Highlight  
This text aims to provide the fundamentals necessary to understand semiconductor device characteristics, operations and limitations. Quantum mechanics and quantum theory are explored, and this background helps give students a deeper understanding of the essentials of physics and semiconductors.

Principles of Electric Machines and Power Electronics

Nanotechnology and Nanoelectronics

Solid State Devices

INTRODUCTION TO SEMICONDUCTOR MATERIALS AND DEVICES

Conventional Transistors and Beyond

Solid State Properties

Split a human hair thirty thousand times, and you have the equivalent of a nanometer. The aim of this work is to provide an introduction into nanotechnology for the scientifically interested. However, such an enterprise requires a balance between comprehensibility and scientific accuracy. In case of doubt, preference is given to the latter. Much more than in microtechnology – whose fundamentals we assume to be known – a certain range of engineering and natural sciences are interwoven in nanotechnology. For instance, newly developed tools from mechanical engineering are essential in the production of nanoelectronic structures. Vice versa, mechanical shifts in the nanometer range demand piezoelectric-operated actuators. Therefore, special attention is given to a comprehensive presentation of the matter. In our time, it is no longer sufficient to simply explain how an electronic device operates; the materials and procedures used for its production and the measuring instruments used for its characterization are equally important. The main chapters as well as several important sections in this book end in an evaluation of future prospects. Unfortunately, this way of separating coherent description from reflection and speculation could not be strictly maintained. Sometimes, the complete description of a device calls for discussion of its potential; the hasty reader in search of the general perspective is therefore advised to study this work's technical chapters as well.

This issue of ECS Transactions includes papers based on presentations from the symposium "Solid-state Electronics and Photonics in Biology and Medicine 6," originally held at the 235th ECS Meeting in Dallas, Texas, May 26-30, 2019. Power electronics, which is a rapidly growing area in terms of research and applications, uses modern electronics technology to convert electric power from one form to another, such as ac-dc, dc-dc, dc-ac, and ac-ac with a variable output magnitude and frequency. Power electronics has many applications in our every day life such as air-conditioners, electric cars, sub-way trains, motor drives, renewable energy sources and power supplies for computers. This book covers all aspects of switching devices, converter circuit topologies, control techniques, analytical methods and some examples of their applications. \* 25% new content \* Reorganized and revised into 8 sections comprising 43 chapters \* Coverage of numerous applications, including uninterruptable power supplies and automotive electrical systems \* New content in power generation and distribution, including



solar power, fuel cells, wind turbines, and flexible transmission  
Devices has been written for the undergraduate students of Electronics and Electrical Engineering. The book caters to introductory and advance courses on Solid State Devices. It is student-friendly and written for those who like to understand the subject from a physical perspective. Even teachers and researchers will benefit immensely from this book. This thoughtfully-organized book provides intense knowledge of the subject with the help of lucid descriptions of theories and solved examples and covers the syllabus of most of the colleges under WBUT.

Modern Semiconductor Devices for Integrated Circuits

Compact Modeling

Basic Principles

Basic Electronics

Power Electronics Handbook

*This volume contains the selected papers resulting from the 7th Annual International Workshop on Materials Science and Engineering, and is focusing on the following six aspects: 1. Various Materials Properties, Processing, and Manufactures; 2. Multifunctional Materials Properties, Processing, and Manufactures; 3. Nanomaterials and Biomaterials; 4. Civil Materials and Sustainable Environment; 5. Electrochemical Valuation, Fracture Resistance, and Assessment; 6. Designs Related to Materials Science and Engineering. This proceeding presents and discusses key concepts and analyzes the state-of-the-art of the field. IWMSE 2021 is an academic conference in a series held once per year. The conference not only provides insights on materials science and engineering, but also affords conduit for future research in these fields. It provides opportunities for the delegates to exchange new ideas and application experiences, to establish business or research relations and to find global partners for future collaboration.*

*Solid state electronic devices* **Solid State Electronic Devices**

*Two books in one! Up-to-date coverage of electrical and electronics systems for all types of aircraft -- plus a full student study guide This thoroughly revised guide offers comprehensive explanations of the theory, design, and maintenance of current aircraft electrical and electronics systems. In-depth details on AC and DC systems for all varieties of aircraft—including the newest models—are provided, along with improved diagrams and helpful troubleshooting techniques. You will get complete coverage of cutting-edge topics, including digital control systems, digital data transfer methods, fiber-optic technology, and the latest flight deck instrumentation systems. A student study guide is also included, featuring a workbook with hundreds of multiple-choice, fill-in-the-blank, and analysis questions.*

*Aircraft Electricity and Electronics, Seventh Edition, covers: •Aircraft storage batteries •Electric wire and wiring practices •Alternating current •Electrical control devices •Digital electronics •Electric measuring instruments •Electric motors, generators, alternators, and inverters •Power distribution systems •Design and maintenance of aircraft electrical systems •Radio theory •Communication and navigation systems •Weather warning and other safety systems*  
*For undergraduate electrical engineering students or for practicing engineers and scientists, interested in updating their understanding of modern electronics. One of the most widely used introductory books on semiconductor materials, physics, devices and technology, this text aims to: 1) develop basic semiconductor physics concepts, so students can better understand current and future devices; and 2) provide a sound understanding of current semiconductor devices and technology, so that their applications to electronic and optoelectronic circuits and systems can be appreciated. Students are brought to a level of understanding that will enable them to read much of the current literature on new devices and applications.*

*Materials, Devices, Measurement Techniques*

*Devices, Circuits and Applications*

*Proceedings of the 7th Annual International Workshop on Materials Science and Engineering, (IWMSE 2021), Changsha, Hunan, China, 21-23 May 2021*

*Solution Manual*

*Converters, Applications, and Design*

*Devices to Systems*

A must-have textbook for any undergraduate studying solid state physics. This successful brief course in solid state physics is now in its second edition. The clear and concise introduction not only describes all the basic phenomena and concepts, but also such advanced issues as magnetism and superconductivity. Each section starts with a gentle introduction, covering basic principles, progressing to a more advanced level in order to present a comprehensive overview of the subject. The book is providing qualitative discussions that help undergraduates understand concepts even if they can't follow all the mathematical detail. The revised edition has been carefully updated to present an up-to-date account of the essential topics and recent developments in this exciting field of physics. The coverage now includes ground-breaking materials with high relevance for applications in communication and energy, like graphene and topological insulators, as well as transparent conductors. The text assumes only basic mathematical knowledge on the part of the reader and includes more than 100 discussion questions and some 70 problems, with solutions free to lecturers from the Wiley-VCH website. The author's webpage provides Online Notes on x-ray scattering, elastic constants, the quantum Hall effect, tight binding model, atomic magnetism, and topological insulators. This new edition includes the following updates and new features: \* Expanded coverage of mechanical properties of solids, including an improved discussion of the yield stress \* Crystal structure, mechanical properties, and band structure of graphene \* The coverage of electronic properties of metals is

expanded by a section on the quantum hall effect including exercises. New topics include the tight-binding model and an expanded discussion on Bloch waves. \* With respect to semiconductors, the discussion of solar cells has been extended and improved. \* Revised coverage of magnetism, with additional material on atomic magnetism \* More extensive treatment of finite solids and nanostructures, now including topological insulators \* Recommendations for further reading have been updated and increased. \* New exercises on Hall mobility, light penetrating metals, band structure

Compact Models for Integrated Circuit Design: Conventional Transistors and Beyond provides a modern treatise on compact models for circuit computer-aided design (CAD). Written by an author with more than 25 years of industry experience in semiconductor processes, devices, and circuit CAD, and more than 10 years of academic experience in teaching compact modeling courses, this first-of-its-kind book on compact SPICE models for very-large-scale-integrated (VLSI) chip design offers a balanced presentation of compact modeling crucial for addressing current modeling challenges and understanding new models for emerging devices. Starting from basic semiconductor physics and covering state-of-the-art device regimes from conventional micron to nanometer, this text: Presents industry standard models for bipolar-junction transistors (BJTs), metal-oxide-semiconductor (MOS) field-effect-transistors (FETs), FinFETs, and tunnel field-effect transistors (TFETs), along with statistical MOS models Discusses the major issue of process variability, which severely impacts device and circuit performance in advanced technologies and requires statistical compact models Promotes further research of the evolution and development of compact models for VLSI circuit design and analysis Supplies fundamental and practical knowledge necessary for efficient integrated circuit (IC) design using nanoscale devices Includes exercise problems at the end of each chapter and extensive references at the end of the book Compact Models for Integrated Circuit Design: Conventional Transistors and Beyond is intended for senior undergraduate and graduate courses in electrical and electronics engineering as well as for researchers and practitioners working in the area of electron devices. However, even those unfamiliar with semiconductor physics gain a solid grasp of compact modeling concepts from this book.

Principles of Electronics

Solid-State Electronic Devices

Solid State

Electromechanical Systems and Devices

Electronic Devices And Circuit Theory,9/e With Cd

Energy Efficient Computing & Electronics